



General Description

The AOZ8020 is an 8-line device integrating EMI filtering with ESD protection for each line. It is designed to suppress unwanted EMI/RFI signals and provide electrostatic discharge (ESD) protection in portable electronic equipment. This state-of-the-art device utilizes AOS leading edge Trench Vertical Structure [TVS]² ™ technology for superior clamping performance and filter attenuation over the full operating display range. The AOZ8020 has been optimized for protection of color LCD displays and CCD camera lines in cellular phones and other portable consumer electronic devices.

The AOZ8020 consists of eight identical circuits comprised of TVS diodes for ESD protection, and a resistor–capacitor network for EMI/RFI filtering. A series resistor value of 100Ω and a capacitance value of 9pF are used to achieve -20dB minimum attenuation from 1.0GHz to 3.0GHz. The TVS diodes provide effective suppression of ESD voltages in excess of ±20kV (air discharge) and ±20kV (contact discharge). This exceeds IEC 61000-4-2, level 4 ESD immunity test.

The AOZ8020 comes in an RoHS compliant, 1.6mm x 4.0mm TDFN package and is rated over a -40°C to +85°C ambient temperature range.

Features

- 8 lines for EMI filtering and ESD protection:
 - Exceeds IEC 61000-4-2, level 4 (ESD) immunity test $-\pm 20$ kV (air discharge) and ± 20 kV (contact discharge)
- Trench Vertical Structure [TVS]² ™ based technology used to achieve excellent ESD clamping & filter performance over the full operating display range
- Filter performance: -20db attenuation from 1.0GHz to 3.0GHz
- Low operating voltage: 5.0V
- Capacitance stability over wide range of voltages and temperatures
- TDFN package: 1.6mm x 4.0mm
- Pb-Free device
- Green product

Applications

- EMI filtering and ESD protection for data lines
- LCD displays, camera interface, I/O interface
- Portable handheld devices, cell phones, PDA phones



Typical Application

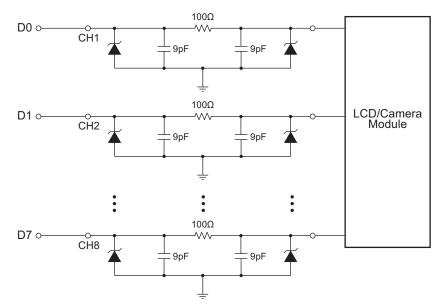


Figure 1.



Ordering Information

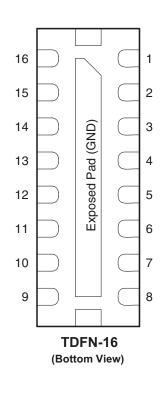
Part Number	Ambient Temperature Range Package		Environmental		
AOZ8020DI	-40°C to +85°C	TDFN-16	RoHS Compliant Green Product		

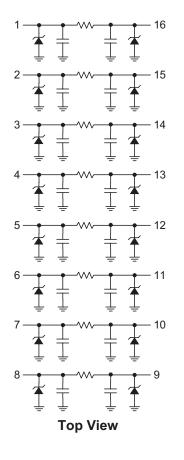


AOS Green Products use reduced levels of Halogens, and are also RoHS compliant.

Please visit www.aosmd.com/web/quality/rohs_compliant.jsp for additional information.

Pin Configuration





Pin Description

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Pin Number	Pin Name	Pin Function		
1,16	CH 1	Channel 1 Connections		
2, 15	CH 2	Channel 2 Connections		
3, 14	CH 3	Channel 3 Connections		
4, 13	CH 4	Channel 4 Connections		
5, 12	CH 5	Channel 5 Connections		
6, 11	CH 6	Channel 6 Connections		
7, 10	CH 7	Channel 7 Connections		
8, 9	CH 8	Channel 8 Connections		
Exposed Pad	GND	Common Ground Connection		



Absolute Maximum Ratings

Exceeding the Absolute Maximum ratings may damage the device.

Parameter	Rating
Storage Temperature (T _S)	-65°C to +150°C
ESD Rating per IEC61000-4-2, contact ⁽¹⁾	±20kV
ESD Rating per IEC61000-4-2, air ⁽¹⁾	±20kV
ESD Rating per Human Body Model ⁽²⁾	±30kV

Notes:

1. IEC 61000-4-2 discharge with C_{Discharge} = 150pF, R_Discharge = 330 Ω .

2. Human Body Discharge per MIL-STD-883, Method 3015 C_{Discharge} = 100pF, R_{Discharge} = $1.5k\Omega$.

Electrical Characteristics

 $T_A = 25^{\circ}C$ unless otherwise specified.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
V _{RWM}	Reverse Working Voltage	(3)			5.0	V
V _{BR}	Reverse Breakdown Voltage	$I_{\rm T} = 1 {\rm mA}^{(4)}$	6	7	8	V
I _R	Reverse Leakage Current	$V_{RWM} = 3.3V$			0.1	μA
V _{CL}	Signal Clamp Voltage	$I_{LOAD} = 1A$, positive clamp ⁽⁵⁾⁽⁸⁾ $I_{LOAD} = 1A$, negative clamp ⁽⁵⁾⁽⁸⁾			7.0 -3.0	V
		$I_{LOAD} = 5A$, positive clamp ⁽⁵⁾⁽⁸⁾ $I_{LOAD} = 5A$, negative clamp ⁽⁵⁾⁽⁸⁾			8.0 -5.0	
		$I_{LOAD} = 12A$, positive clamp ⁽⁵⁾⁽⁸⁾ $I_{LOAD} = 12A$, negative clamp ⁽⁵⁾⁽⁸⁾			10.0 -10.0	
R _{CH}	Total Series Resistance	I _R = 20mA	90	100	110	Ω
C _{CH}	Channel Capacitance	Input to Ground ⁽⁶⁾⁽⁷⁾⁽⁸⁾	8	9	10	pF
f _C	Cut-off Frequency	Measured with 50 Ω source and 50 Ω load termination		250		MHz
	Attenuation from 1.0GHz to 3.0GHz	V_{R} = 0V Measured with 50 Ω source and 50 Ω load termination		-20		dB

Notes:

3. The working peak reverse voltage, V_{RWM}, should be equal to or greater than the DC or continuous peak operating voltage level.

4. V_{BR} is measured at the pulse test current I_T.

5. Measurements performed using a 100ns Transmission Line Pulse (TLP) system.

6. Total capacitance is equal to $2 \times C_{CH}$.

7. Measured at 25°C, $V_R = 2.5V$, f = 1.0MHz.

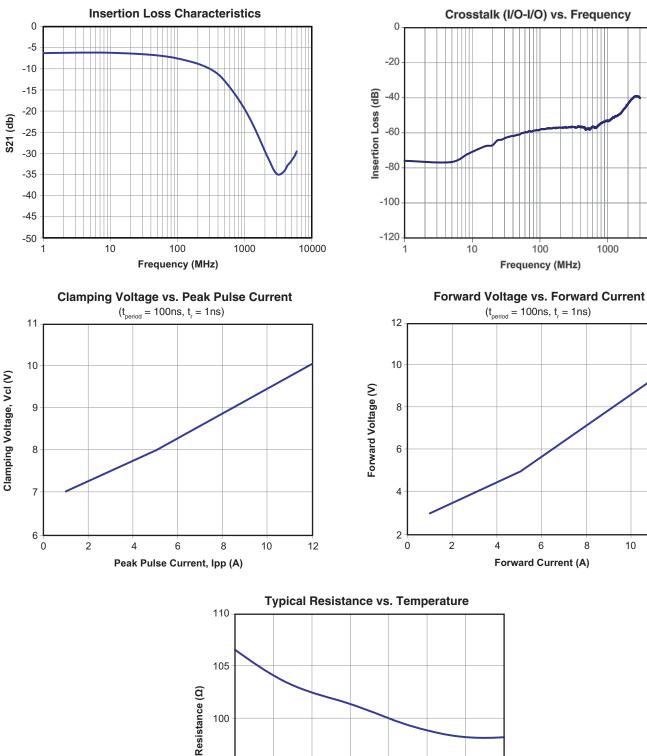
8. Guaranteed by design.

10000

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Typical Performance Characteristics

ALPHA & OMEGA SEMICONDUCTOR



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Temparature (°C)

25

45

65

85

95

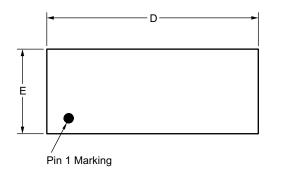
90 **–** -45

-25

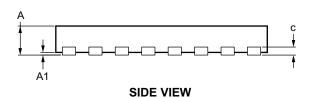
-5

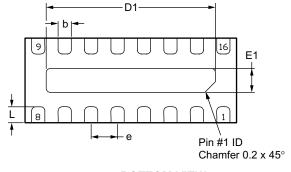


Package Dimensions, TDFN 1.6 x 4.0, 16L



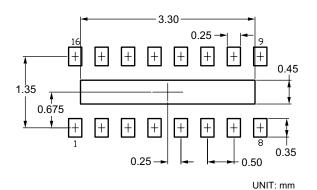
TOP VIEW





BOTTOM VIEW

RECOMMENDED LAND PATTERN



Symbols Min. Nom. Max. 0.55 А 0.50 0.60 A1 0.00 0.05 _ 0.20 0.30 b 0.25 0.152 REF С 4.00 4.05 D 3.95 Е 1.55 1.60 1.65 D1 3.15 3.20 3.25 E1 0.40 0.45 0.50 0.50 BSC е 0.30 L 0.25 0.35

Dimensions in millimeters

Dimensions in inches

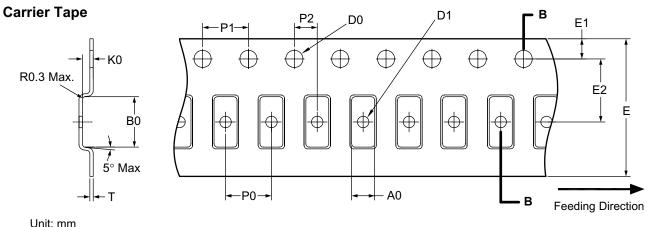
Symbols	Min.	Nom.	Max.	
А	0.020	0.022	0.024	
A1	0.000	—	0.002	
b	0.008	0.010	0.012	
С	0	=.		
D	0.156	0.157	0.159	
E	0.061	0.063	0.065	
D1	0.124	0.126	0.128	
E1	0.016	0.018	0.020	
е	0	.020 BS	C	
L	0.010	0.012	0.014	

Note:

1. Controlling dimension is millimeter. Converted inch dimensions are not necessarily exact.

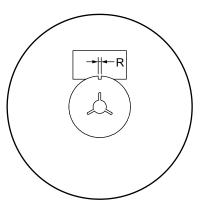


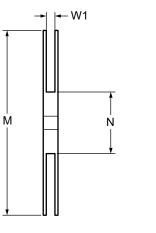
Tape & Reel Dimensions, TDFN 1.6 x 4.0, 16L

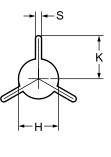


Package	A0	B0	K0	D0	D1	Е	E1	E2	P0	P1	P2	т
DFN	2.00	4.40	0.95	ø1.50	ø1.00	12.00	1.75	5.50	4.00	4.00	2.00	0.30
4x1.6	±0.1	±0.1	±0.1	+0.1/-0	+0.1/-0	±0.3	±0.10	±0.1	±0.10	±0.10	±0.10	±0.05

Reel



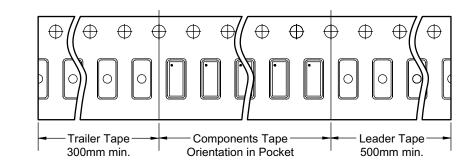




Unit: mm

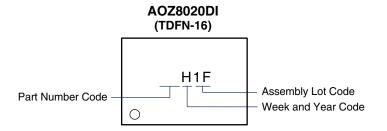
Tape Size	Reel Size	м	N	W1	н	S	к	R
12mm	ø330	ø330.00	55.00	12.4	13.00	2.20	10.60	_
		±0.30/-4.00	±0.40	+2.0/-0	±0.20	±0.20	±0.20	

Leader / Trailer & Orientation





Part Marking



Alpha & Omega Semiconductor reserves the right to make changes to this data sheet at any time without notice.

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As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user. 2. A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.